

# ASM1153E Datasheet



USB3.0 to SATA Bridge Controller

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Environmentally hazardous materials are not used in this product.



# **Revision History**

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0.2 August 9, 2013 Add t	Release
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Upda Upad	te the Vcore spec te the unit of IIL-UP/IIL-DN of GPIO
	te the POS spec
	he notice of LDO regulator in the section of electrical spec
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#### 1. General Description

Engaged in Universal Serial Bus I/O solution and storage application development, ASMedia Technology is committed to expand product portfolio with introducing a new generation of USB3.0 to SATA 6Gbps bridge products.

ASM1153E is the ASMedia third generation single chip solution, bridging the USB3.0 to Serial ATA host interface with highly integrated SuperSpeed USB3.0, High Speed USB2.0 and SATA1.5/3.0/6.0 Gbps ASMedia self-designed PHYs. Along with excellent compatibility with USB3.0 hosts and SATA devices, ASM1153E uses advanced process technology to optimize the chip power consumption. Furthermore, it is also pin-to-pin backward compatible with existing ASM1053.

Customers can easily enhance their storage device performance with ASM1153E since it also integrates an 8-bit micro-processor and embedded RAM to provide a cutting edge solution in USB to SATA device enclosure market.

#### 2. Features

- ♦ Compliant with USB3.0 Specification Revision 1.0
- ♦ Compliant with USB Specification Revision 2.0
- Support USB Super-Speed, High-Speed and Full-Speed Operation
- Support USB Mass Storage Class, Bulk-Only Transport Specification Revision 1.3
- Support USB Attached SCSI Protocol Specification Revision 1.0
- ♦ Compliant with Serial ATA Specification Revision 3.0
- Serial ATA bus up to 6Gbps Signal bandwidth
- ♦ Support Spread Spectrum Control of USB3.0 and SATA interface to improve the EMI performance
- Support ATA/ATAPI Packet Command Set
- Support ATA/ATAPI LBA48 addressing mode
- ♦ Integrated 8-bit micro-processor with embedded program RAM and ROM
- ♦ Support SPI NVRAM for Vender Specific Application of USB Device Controller
- ♦ Support multi-GPIO pins
- Support programmable PWMs
- Support 20/25/30MHz with external crystal mode or 30MHz with Clock input mode via strapping
- ♦ Integrated two internal voltage regulator for IO power and Core
- ♦ HBM ESD 2KV and MM ESD 200V

## 3. Package Type

Green Package 6x6 QFN 48L (Pb-free)



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# 4. Functional Diagram

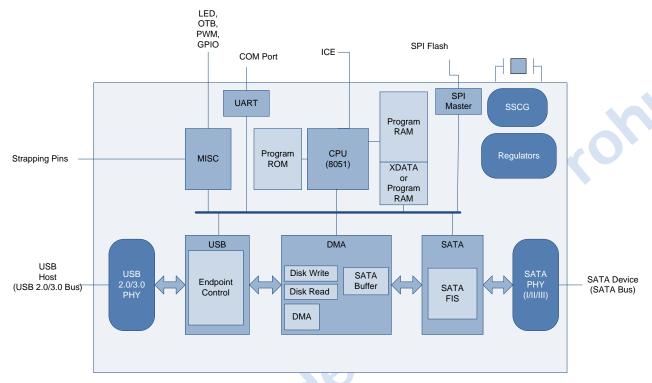


Figure 1: Functional Diagram of ASM1153E

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# 5. Pinout Diagrams

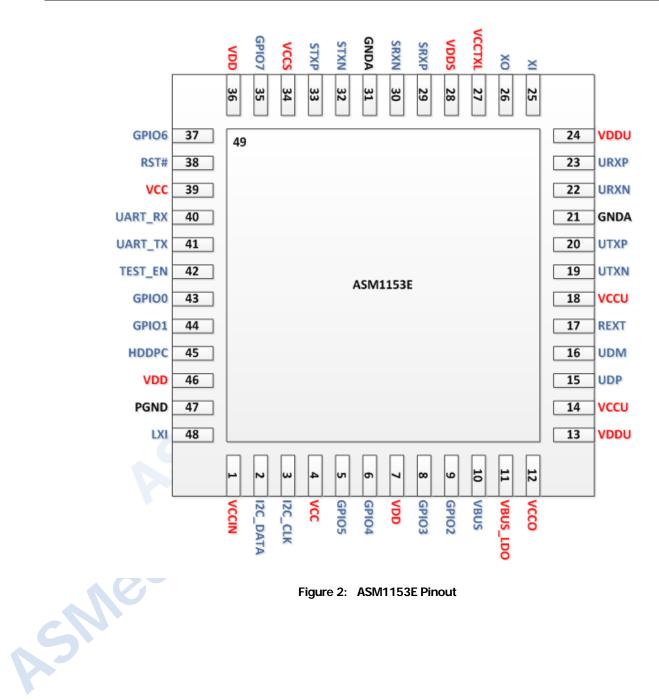


Figure 2: ASM1153E Pinout



# 6. Pin Descriptions

I/O Type	Definition
	Input pin
0	Output pin
В	Bi-directional pin
Р	Power pin
G	Ground pin
OD	Open Drain

ype D	efinition		
	nput pin		
	utput pin		
	i-directional pin		
	ower pin		
	round pin		
	pen Drain		
U	реп Бтапт		
Pin No.	Name	TYPE	Descriptions
ISB interfa			Descriptions
16	UDM	DB	USB2.0 negative Data Signal
15	UDP	DB	USB2.0 positive Data Signal
19	UTXN	DO	SuperSpeed USB negative Transmitter Signal
20	UTXP	DO	SuperSpeed USB positive Transmitter Signal
22	URXN	DI	SuperSpeed USB negative Receiver Signal
23	URXP	DI	SuperSpeed USB positive Receiver Signal
ATA inter			
29	SRXP	DI	SATA positive Receiver Signal
30	SRXN	DI	SATA negative Receiver Signal
32	STXN	DO	SATA negative Transmitter Signal
33	STXP	DO	SATA positive Transmitter Signal
ystem Sig			
42	TEST_EN	I	Test Enable Signal, with internal pull-down resistor
	_		0: Normal Mode (Default)
			1: Test Mode Enable
2	I2C_DATA	В	Used as I2C_DATA signal or SPI_DI signal, defined by strapping pin 37
			GPIO6. Used as General Purpose IO after power on. Integrated pull-up
			resistor.
3	I2C_CLK	В	Used as I2C_CLK signal or SPI_CLK signal, defined by strapping pin 37
			GPIO6. Used as General Purpose IO after power on. Integrated pull-up
			resistor.
5	GPI05	В	General Purpose IO, used as SPI_DO, with internal pull-up resistor.
6	GPIO4	В	General Purpose IO, used as SPI_CSO, with internal pull-up resistor.
8	GPIO3	В	General Purpose IO, used as strapping pin for clock source select while
40			power on. Refer to the strapping table. Integrated pull-up resistor.
9	GPIO2	В	General Purpose IO, used as SPI_CS1, with internal pull-up resistor.
35	GPIO7	В	General Purpose IO, use as strapping for clock source select while power
			on. Refer to the strapping table. Integrated pull-up resistor.
37	GPIO6	В	General Purpose IO, used as strapping for external ROM enabling via SPI
			interface. Refer to the strapping table. Integrated pull-up resistor.
40	UART_RX	В	URAT_RX while debug mode, Used as General Purpose IO after power on.
			Integrated pull-up resistor.
41	UART_TX	В	UART_TX while debug mode, Used as General Purpose IO after power on.
	_		Integrated pull-up resistor.
43	GPIO0	В	General Purpose IO. Integrated pull-up resistor.
44	GPIO1	В	General Purpose IO. Integrated pull-up resistor.
45	HDDPC	В	HDD power control pin, use as General Purpose IO. Integrated pull-up
			resistor.
			0: Hard Drive Power Off
			1: Hard Drive Power On
10	VBUS	I	USB Cable Power Detector
10 17 38	VBUS REXT RST#	l P	USB Cable Power Detector  External Reference Resistor with 12.1Kohm +/-1%  Power Reset pin



Pin No.	Name	TYPE	Descriptions
25	ΧI	I	Crystal input or Clock input pin
26	XO	0	Crystal output or Clock output pin
27	VCCTXL	Р	Power for Crystal and PLL circuit
Voltage Regu	lator		
11	VBUS_LDO	Р	Linear regulator input
12	VCCO	Р	Linear regulator output
1	VCCIN	Р	Switching regulator input
48	LXI	Р	Connect with external inductor
47	PGND	G	Ground for voltage regulator
Power and Gr	round		
14, 18	VCCU	Р	USB high power pin
34	VCCS	P	SATA high power pin
13, 24	VDDU	Р	USB low power pin
28	VDDS	Р	SATA low power pin
7, 36, 46	VDD	Р	Core power
4, 39	VCC	Р	IO power
21, 31	GNDA	G	Analog Ground
49	GND	G	the exposed pad connected to common ground on PCB

## 6.1 Strapping Table

Pin	F Al				
	Function	Description			
CDIO4	CDI Interface Coloct	0: SPI for External ROM			
GPIO6	SPI Interface Select	1: I2C (Default)			
		00: 25MHz Crystal			
GPIO[3,7]	Clock Select	01: 30MHz Clock Input			
GPIO[3,7]	Clock Select	10: 20MHz Crystal			
		11: 30MHz Crystal (Default)			



#### 7. Electrical Characteristics

#### 7.1 Absolute Maximum Ratings

Stresses the below parameter listed under absolute maximum rating may cause the device permanent damage. This is a stress rating only, and the function operating of the device at these or any other conditions over those parameter in the recommended operating condition is not implied. It is recommended to have a clamp circuit to protect the device with abnormal exhibit voltage spikes while power is switched on or off.

Parameter	Range	Unit	
Power Supply for VCC	-0.5 ~ VCC+0.5	V	
Power Supply for VDD	-0.5 ~ VDD+0.5		
DC Input Voltage	-0.5 ~ VCC+0.5	V	
Output Voltage	-0.5 ~ VCC+0.5	V	
Storage Temperature	JEDEC J-STD-033B MSL 3		

## 7.2 Recommended Operating Conditions

Symbols	Parameter	Min.	Тур.	Max.	Units
Vcc	IO Power Supply	2.3	3.3	3.6	V
<b>V</b> ccu	USB Analog High Power Supply	2.3	3.3	3.6	V
Vccs	SATA Analog High Power Supply	2.3	3.3	3.6	V
<b>V</b> DD	Core Power Supply	1.0	1.05	1.28	V
<b>V</b> DDU	USB Analog Low Power Supply	1.0	1.05	1.28	V
<b>V</b> DDS	SATA Analog Low Power Supply	1.0	1.05	1.28	V
Tc	Operating Case Temperature	0	25	95	°C
LΊ	Operating Junction Temperature	0	25	120	°C
НВМ	Human Body mode ESD		+/-2		KV
MM	Machine Mode ESD		+/-200		V

#### 7.3 DC Electrical Characteristics for VBUS pins

Symbols	Parameter	Min.	Тур.	Max.	Units
ViH	Input High Level	2			V
VIL	Input Low Level			0.8	V
VHYS	Input Hysteresis	0.57	0.6	0.65	mV
V <sub>TH-L2H</sub>	VTH of Schmitt Trigger low to high	1.4		1.8	V
VTH-H2L	VTH of Schmitt Trigger high to low	0.85		1.10	V

#### 7.4 DC Electrical Characteristics for GPIO pins

Cumbala	Parameter	V	CC=3.3	V	V	Units		
Symbols		Min.	Тур.	Max.	Min.	Тур.	Max.	Units
Vін	Input High Level	2			1.55			V
VIL	Input Low Level			0.8			0.6	V
<b>V</b> HYS	Input Hysteresis	0.57	0.6	0.65	0.47	0.52	0.57	mV
<b>V</b> TH-L2H	VTH of Schmitt Trigger low to high	1.38	1.6	1.8	1.1	1.3	1.5	V
<b>V</b> TH-H2L	VTH of Schmitt Trigger high to low	0.89	1.07	1.22	0.63	0.78	0.94	V
<b>D</b>	Internal Pull-up resistance while Vin=0V	70	103	143	97	148	216	ΚΩ
Rup	Internal Pull-up resistance while Vin=VCC/2 V	40	58.2	79.2	53	80	115	ΚΩ



Symbols	Parameter	V	CC=3.3	/	V	Units		
Symbols	i di diffictei	Min.	Тур.	Max.	Min.	Тур.	Max.	Ullits
Rdn	Internal Pull-down resistance while Vin=0V	68	109	158	91	153	230	ΚΩ
	Internal Pull-down resistance while Vin=VCC/2 V	39	61.7	88	49	82.7	123	ΚΩ
I IL-UP	Input pull-up current after Vin is read, Rup is off & Iil < 1uA when VIN=0	21	32	54	10	16.8	32	mA
	Input pull-up current after Vin is read, Rup is off & Iil < 1uA when VIN=VCC/2	19	28.4	48	9.8	15.6	28	mA
_	Input pull-down current after Vin is read, Rdn is off & Iil < 1uA when VIN=VCC	19	30.2	54	15.4	27.8	32	mA
IIL-DN	Input pull-down current after Vin is read, Rdn is off & Iil < 1uA when VIN=VCC/2	17	26.8	48	9.6	16.4	29	mA

# 7.5 DC Electrical Characteristics for RST# pins

Symbols	Parameter	Min.	Тур.	Max.	Units
<b>V</b> IH	Input High Level	2.6			V
VIL	Input Low Level	ZY		1.4	V
<b>V</b> HYS	Input Hysteresis	0.218	0.235	0.25	V
<b>V</b> TH-L2H	VTH of Schmitt Trigger low to high	1.88		2.58	V
<b>V</b> TH-H2L	VTH of Schmitt Trigger high to low	1.65		2.35	V
Iιι	Input pull-up leakage current while Vin=0V			1	uA

#### 7.6 External Crystal Electrical Specification

Note: please refer to the figure 3

Symbol	Parameter	Min.	Тур	Max.	Unit
<b>f</b> xtal	Frequency		20/25/30		MHz
$\Delta f$ XTAL	Long Term Stability (at 25°C)	-30		30	ppm
Tc	Temperature Stability	-30		30	ppm
FA	Aging	-5		5	ppm
CL	Load Capacitance (Single-end mode)		16		pF
Co	Shunt Capacitance	1	3	7	pF

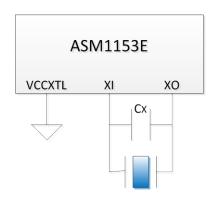


Figure 3: Differential Crystal Design



#### 7.7 Differential Clock Oscillator Electrical Specification

Note: please refer to the figure 3

Note. pi	case refer to the rigare s				1		
Symbol	Parameter		Min.	Тур	Max.	Unit	
<b>f</b> clk	Frequency			20/25/30		MHz	
∆fc∟ĸ	Long Term Stability (all condition)		-150		150	ppm	
Сх	External Load Capacitance (Differential mode)			10		pF	
Стотац	Total External Equivalent Capacitance from XI pin (Differential mode)	n to XO	9	11	15	Pf	N
RTOTAL	Total External Equivalent Series Resistance from to XO pin	XI pin			60	Ω	
Exterr	nal Clock Input Electrical Spe	ecificat	tion				
Symbol	Parameter	Min.	Тур	o Ma	x.	Unit	
fclk	Frequency		30			MHz	

## 7.8 External Clock Input Electrical Specification

Symbol	Parameter	Min.	Тур	Max.	Unit
fclk	Frequency		30		MHz
∆fc∟ĸ	Long Term Stability (all condition)	-100	61	100	ppm
Jitter	Input Clock cycle to cycle jitter Tolerance			150	ps
	Duty Cycle	45		55	%
<b>t</b> R	Rising Edge rate	1.0	0	2.0	V/ns
tr	Falling Edge rate	1.0		2.0	V/ns
Vih	Clock Input High Level	2			V
VIL	Clock Input Low Level			0.8	V

#### 7.9 Internal Linear Regular Electrical Specification

Symbol	Parameter	Min.	Тур	Max.	Unit
VIN_LINEAR	Input Voltage Range for internal linear regulator	4.5	5	5.5	V
Vout_linear	Output Voltage Range for internal linear regulator	3.15	3.3	3.45	V
Імах	Maximum capacity of current output			200	mA

Notice: Please make sure the VCCIN is tied to 5V, even it uses the external 5V to 3.3V regulator.

#### 7.10 Internal Switching Regular Electrical Specification

4	Symbol	Parameter	Min.	Тур	Max.	Unit
	V <sub>IN_</sub> SWITCH	Input Voltage Range for internal switching regulator	2.3		5.5	V
	Vout_switch	Output Voltage Range for internal switching regulator	1.0	1.05	1.1	V
	ΔVn (р-р)	3.3V input voltage noise/ripple Range	-8		8	%
	Fosc	OSC frequency		1.7		MHz
	IMAX	Maximum capacity of current output			300	mA
	IP <sub>(LM)</sub>	P-channel current limiter		1		А

Strong recommendation to have 10uF decoupling capacitor placed close to pin3 to filter the noise/ripple of 3.3V switching regulator input.



#### 7.11 Power Consumption Characteristics

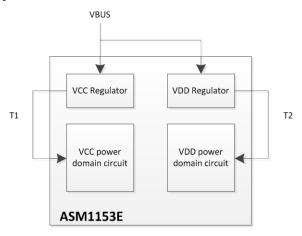


Figure 4: Test point for power consumption

	T1 Fig	VCC powdomain circle  ASM1153	eer rcuit	VDD Regulato  VDD power domain circu	it	Т2				1105
Symbols	Parameter	Condition		USB3.0			USB2.0		Units	
			Min.	Тур.	Max.	Min.	Тур.	Max.		
	Total current	Operating	30	40	50	17	27	37	mA	
Ivcc	consumed for 3.3V	Idle	30	40	50	17	27	37	mA	
1000	power domain (Test point T1)	Suspend	1.0	1.5	2.5	1.0	1.5	2.5	mA	
	Total current	Operating	150	170	190	83	98	113	mA	
Ivdd	consumed for 1.05V	Idle	110	125	140	83	98	113	mA	
. 100	power domain (Test point T2)	Suspend	1,5	2.5	3.8	1.5	2.5	3.8	mA	

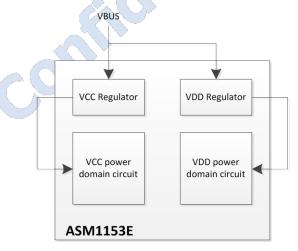


Figure 5: Test point on Type 1

	Ne		VCC power domain circle  ASM1153  Figure 5:	uit E	VDD power domain circuit					
	Symbols	Parameter	Condition		USB3.0			USB2.0		Units
				Min.	Тур.	Max.	Min.	Тур.	Max.	
		Total current	Operating	75	85	95	65	75	85	mA
	Iveus consumption for 5V		Idle	65	75	85	65	75	85	mA
			Suspend	1.5	2.5	3.5	1.5	2.5	3.5	mA
	Total power			375	425	475	325	375	425	mW
			Idle	325	375	425	325	375	425	mW
		(Test Point: Vbus)	Suspend	7.5	12.5	17.5	7.5	12.5	17.5	mW



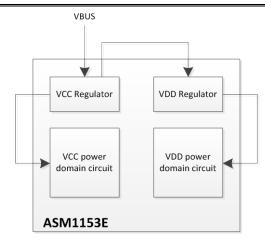


Figure 6: Test point for Type 2

		VCC Regula  VCC power domain circ  ASM1153  Figure 6:	er xuit	VDD Regulat  VDD power domain circu	riit					1105
Symbols	Parameter	Condition		USB3.0			USB2.0		Units	
			Min.	Тур.	Max.	Min.	Тур.	Max.		ı
	Total current	Operating	95	105	115	75	85	95	mA	
IvBus	consumption for 5V	Idle	75	85	95	75	85	95	mA	
	(Test Point: Vbus)	Suspend	1.5	2.5	3.5	1.5	2.5	3.5	mA	
	Total power	Operating	475	525	575	375	425	475	mW	
PvBus	consumption for 5V	Idle	375	425	475	375	425	475	mW	
	(Test Point: Vbus)	Suspend	7.5	12.5	17.5	7.5	12.5	17.5	mW	

inal swi Notice: Different types of inductors used for internal switching regulator will have varying power consumption



# 8. Power on Sequence

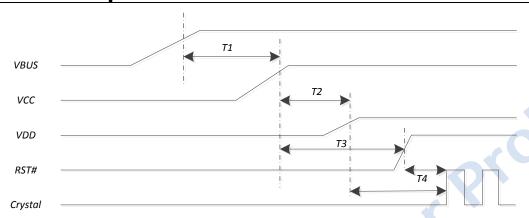


Figure	7:	timina	diagram
94.0			alagi ai i i

			Figure	e /: tii	ming di	agram	
	Symbols	Parameter	Min	Тур	Max	Unit	Remark
	T1	The delay of VCC after VBUS is available	0	5	10	ms	Measure from 10% of VCC to 90% of VBUS For Self-powered system or external 5V to VCC regulator, this rule is not needed.
	Т2	The delay of VDD after VCC is available	N/A		90	ms	Measure from 10% of VCC to 90% of VDD For external VCC to VDD regulator, this rule is not needed.
	Т3	The delay of RST# after VCC is available	0		N/A	ms	Measure from 90% of RST# to 90% of VCC
	Т4	The crystal clock is stable after RST# and VDD is available	15	25	40	ms	Measure from 90% of VDD or 2V of RST#
	Tslew	Slew rate of VDD	0		10	ms	Measure from 10% to 90% of VDD
A.		, dia					



# 9. PCB Design Guide under Thermal Pad

To improve the thermal efficieny and signal integrity, it is recommended to place the thermal via under or near to thermal pad. To avoid the process issue, please make sure the thermal via fills with solder covering with solder mask. It is recommended to follow up the pattern on PCB as Figure 7 or Figure 8.

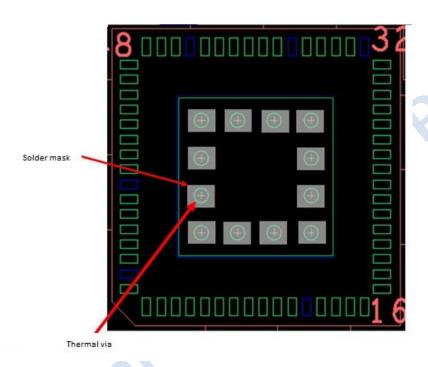


Figure 8: Symbol 1 for via design rule under Thermal pad

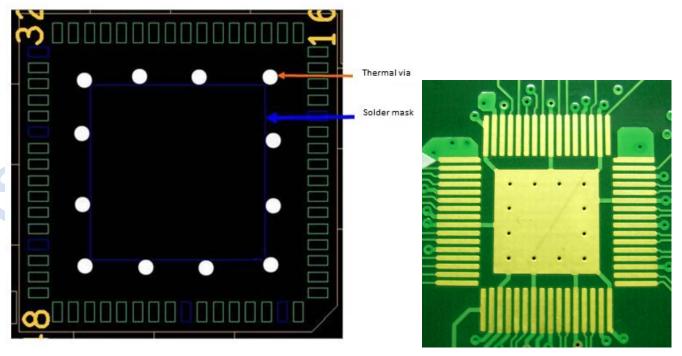
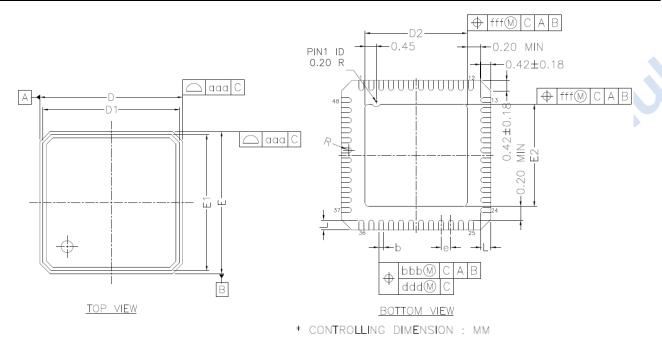
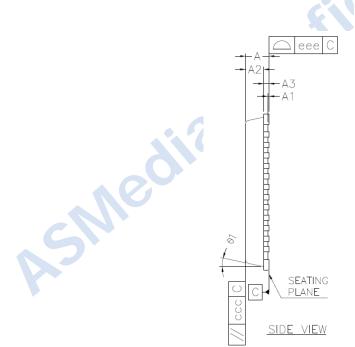


Figure 9: Symbol 2 for via design rule under Thermal pad



# 10. Package Information





	1.01	HACTE	-	Ι	INTOLL		
SYMBOL		LIMETE			INCH		
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	
А	0.80	0.85	0.90	0.031	0.033	0.035	
A1	0.00	0.02	0.05	0.00	0.001	0.002	
A2	0.60	0.65	0.70	0.024	0.026	0.028	
А3	0	).20 R	EF.	(	0.008	REF.	
b	0.15	0.20	0.25	0.006	0.008	0.010	
D	6	6.00 b	SC	(	).236	bsc	
D1	5	.75 b	sc	(	).226	bsc	
D2	3.95	4.10	4.25	0.156	0.161	0.167	
E	6	6.00 b	SC	0.236 bsc			
E1	5	.75 b	sc	(	).226	bsc	
<b>E</b> 2	3.95	4.10	4.25	0.156	0.161	0.167	
L	0.30	0.40	0.50	0.012	0.016	0.020	
е	0	).40 b:	SC	0.	016 Ь	SC	
<del>0</del> 1	0,		14"	0,		14*	
R	0.075			0.003			
TOI	ERANC	ES OF	FORM	AND	POSITIO	ON	
aaa			0.10			0.004	
bbb			0.07			0.003	
CCC			0.10			0.004	
ddd			0.05			0.002	
eee			0.08			0.003	
fff			0.10			0.004	



NOTES:

1.ALL DIMENSIONS ARE IN MILLIMETERS.

2.DIE THICKNESS ALLOWABLE IS 0.305 mm MAXIMUM(.012 INCHES MAXIMUM)

3.DIMENSIONING & TOLERANCES CONFORM TO ASME Y14.5M. -1994.

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# 11. Top Marking Information

TBD



